



**Product data sheet** 

sym027

### 1. Product profile

#### 1.1 General description

Two planar PIN diodes in common cathode configuration in a SOT23 small SMD plastic package.

#### 1.2 Features

- High voltage; current controlled
- Low diode capacitance
- Low series inductance

### **1.3 Applications**

RF attenuators and switches

### 2. Pinning information

Pin	Description	Simplified outline	Symbol	
1	anode (a1)	—	_	
2	anode (a2)		3	
3	common cathode			

### 3. Ordering information

Table 2.         Ordering information				
Type number	Package			
	Name	Description	Version	
BAP70-05	-	plastic surface-mounted package; 3 leads	SOT23	

### 4. Marking

Table 3. Marking	
Type number	Marking code
BAP70-05	8Кр



# 5. Limiting values

Table 4.Limiting valuesIn accordance with the Absolute Maximum Rating System (IEC 60134).				
Parameter	Conditions	Min	Max	Unit
reverse voltage	continuous voltage	-	50	V
forward current	continuous current	-	100	mA
total power dissipation	$T_{sp} = 90 \ ^{\circ}C$	-	250	mW
storage temperature		-65	+150	°C
junction temperature		-65	+150	°C
	ce with the Absolute Maxin Parameter reverse voltage forward current total power dissipation storage temperature	ce with the Absolute Maximum Rating System (IECParameterConditionsreverse voltagecontinuous voltageforward currentcontinuous currenttotal power dissipation $T_{sp} = 90 \ ^{\circ}C$ storage temperature	ce with the Absolute Maximum Rating System (IEC 60134).ParameterConditionsMinreverse voltagecontinuous voltage-forward currentcontinuous current-total power dissipation $T_{sp} = 90 ^{\circ}C$ -storage temperature-65	ce with the Absolute Maximum Rating System (IEC 60134).ParameterConditionsMinMaxreverse voltagecontinuous voltage-50forward currentcontinuous current-100total power dissipation $T_{sp} = 90 \ ^{\circ}C$ -250storage temperature-65+150

## 6. Thermal characteristics

Table 5.	Thermal characteristics			
Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		220	K/W

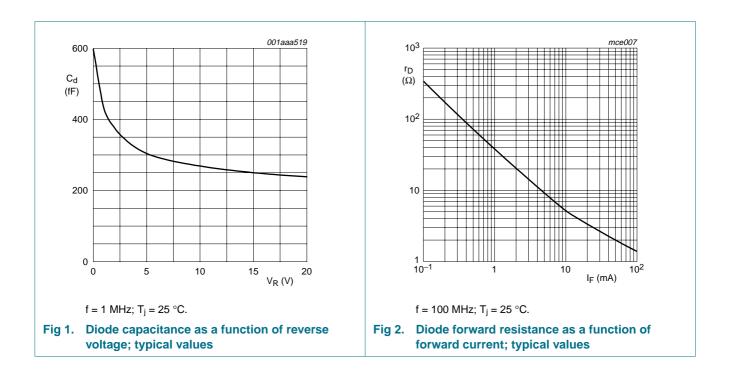
## 7. Characteristics

#### Table 6. Characteristics

 $T_{amb} = 25 \circ C$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 50 mA	-	0.95	1.1	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 50 V	-	-	100	nA
C <sub>d</sub>	diode capacitance	see <u>Figure 1;</u> f = 1 MHz;				
		$V_R = 0 V$	-	600	-	fF
		V <sub>R</sub> = 1 V	-	430	-	fF
		V <sub>R</sub> = 20 V	-	250	300	fF
r <sub>D</sub>	diode forward resistance	see Figure 2; f = 100 MHz;				
		I <sub>F</sub> = 0.5 mA	-	77	100	Ω
		I <sub>F</sub> = 1 mA	-	40	50	Ω
		I <sub>F</sub> = 10 mA	-	5.4	7	Ω
		I <sub>F</sub> = 100 mA	-	1.4	1.9	Ω
τ∟	charge carrier life time	when switched from I <sub>F</sub> = 10 mA to I <sub>R</sub> = 6 mA; R <sub>L</sub> = 100 $\Omega$ ; measured at I <sub>R</sub> = 3 mA	-	1.25	-	μs
L <sub>S</sub>	series inductance	I <sub>F</sub> = 100 mA; f = 100 MHz	-	1.4	-	nH

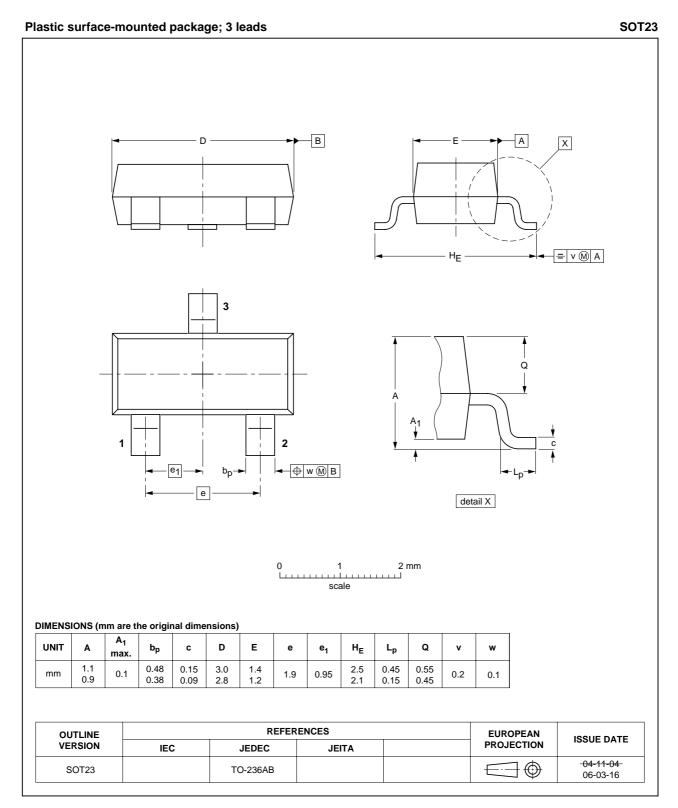
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**BAP70-05** 

Silicon PIN diode

### 8. Package outline



#### Fig 3. Package outline SOT23

## 9. Abbreviations

Table 7. A	bbreviations
Acronym	Description
PIN	P-type, Intrinsic, N-type
SMD	Surface Mounted Device
RF	Radio Frequency

# **10. Revision history**

Table 8. Revision hist	ory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP70-05_3	20070405	Product data sheet	-	BAP70-05_2
Modifications:	• <u>Table 6</u> : chan	ged I <sub>R</sub> maximum value from 20	) nA to 100 nA	
BAP70-05_2	20061221	Product data sheet	-	BAP70-05_1
Modifications:		this data sheet has been rede NXP Semiconductors.	signed to comply with the	ne new identity
	<ul> <li>Legal texts had</li> </ul>	ave been adapted to the new co	ompany name where ap	propriate.
	<ul> <li>Figure 2 replace</li> </ul>	aced		
BAP70-05_1 (9397 750 12811)	20040405	Product data sheet	-	-

## **11. Legal information**

#### 11.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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## BAP70-05 Silicon PIN diode

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